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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09 787,358		Philip Marriott	Q63472	7859
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SUGHRUE MION, PLLC			EXAMINER	
1010 EL CAMINO REAL, SUITE 300 MENLO PARK, CA 94025			QUASH, AN	THONY G
			ART UNIT	PAPER NUMBER
			2881	

Please find below and/or attached an Office communication concerning this application or proceeding.

		_ ILL/			
	Application No.	Applicant(s)			
	09/787,358	MARRIOTT, PHILIP			
Office Action Summary	Examiner	Art Unit			
	Anthony Quash	2881			
The MAILING DATE of this communication a Period for Reply	ppears on the cover sheet w	th the correspondence address			
A SHORTENED STATUTORY PERIOD FOR REF THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication - If the period for reply specified above is less than thirty (30) days, a ri - If NO period for reply is specified above the maximum statutory perion - Failure to reply within the set or extended period for reply will, by stat - Any reply received by the Office later than three months after the mail earned patent term adjustment See 37 CFR 1 704(b) Status	1. 1.136(a) In no event however, may a eply within the statutory minimum of thir od will apply and will expire SIX (6) MON tute, cause the application to become A.	reply be timely filed by (30) days will be considered timely ITHS from the mailing date of this communication BANDONED (35 U S C § 133)			
1) Responsive to communication(s) filed on 09	9 July 2002 .				
2a) This action is FINAL . 2b)	This action is non-final.				
3) Since this application is in condition for allo closed in accordance with the practice under					
Disposition of Claims	P O				
4) Claim(s) <u>1-6 and 8-26</u> is/are pending in the					
4a) Of the above claim(s) is/are withdo	rawn from consideration.				
5) Claim(s) is/are allowed.					
6)⊡ Claim(s) <u>1-6 and 8-26</u> is/are rejected.					
7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and Application Papers	d/or election requirement.				
9) The specification is objected to by the Examin	ner.				
10) The drawing(s) filed on is/are: a) acc		he Examiner.			
Applicant may not request that any objection to					
11) The proposed drawing correction filed on					
If approved, corrected drawings are required in					
12) The oath or declaration is objected to by the I					
Priority under 35 U.S.C. §§ 119 and 120					
13) Acknowledgment is made of a claim for fore	ign priority under 35 U.S.C.	§ 119(a)-(d) or (f).			
a) All b) Some * c) None of:					
1. Certified copies of the priority documents have been received.					
2. Certified copies of the priority documents have been received in Application No					
Copies of the certified copies of the prapplication from the International I See the attached detailed Office action for a li	riority documents have beer Bureau (PCT Rule 17.2(a)).	received in this National Stage			
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).					
a) ☐ The translation of the foreign language p 15)☐ Acknowledgment is made of a claim for dome	provisional application has b	een received.			
Attachment(s)	some priority under 50 0.0.0	33 .20 dildioi 12 i.			
1) Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449) Paper No(s	5) Notice of	Summary (PTO-413) Paper No(s) Informal Patent Application (PTO-152)			

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DETAILED ACTION

Claim 7 has been canceled by applicants' amendment in paper number 11.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-5 and 13-20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Eiden [091]. As per claim 1, Eiden [091] teaches a mass spectrometer comprising; means for generating ions (900) from a sample introduced into a plasma, a sampling aperture (20) for transmitting some of the ions into an evacuated expansion chamber (15) along a first axis to form an ion beam; a second aperture (3) for transmitting some of the ion beam into a first evacuated chamber, a first pump for maintaining the first evacuated chamber at high vacuum, a first ion optical device being located in the first evacuated chamber (15) for containing the ion beam wherein the first ion optical device is a mass selective device, a third aperture (40) for transmitting the ion beam into a second evacuated chamber (25) at a lower pressure than the first evacuated chamber (15); a collision cell (710) having an entrance aperture (740) and an exit aperture (770) and pressurized with a target gas, the collision cell (710) being disposed in the second evacuated chamber (25); a second ion optical device (720) located in the collision cell for containing the ion beam; and fourth aperture for

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transmitting the ion beam into a third evacuated chamber (35) containing mass-to-charge ratio analyzing means (10) disposed along an axis for mass analyzing the ion beam to produce a mass spectrum of the ion beam. Although Eiden [091] does not specifically state that the mass-to-charge ratio analyzing means operate at the same mass to charge ratio, it would have been obvious to one of ordinary skill in the art at the time the invention was made to analyze the beam at the analyte mass to charge ratio in order to see a spectrum of the ions of interest. In addition, Eiden [091] teaches a third pump for maintaining the third evacuated chamber at lower pressure than the second evacuated chamber. See Eiden [091] abstract, figs. 1,3-4,7, col. 4 lines 1-20 and 34-40, col. 8 lines 24-67, col. 9 lines 1-40, col. 10 lines 25-41, col. 12 lines 25-40, col. 15 lines 15-40.

As per claim 2, Eiden [091] teaches all aspects of the claim except for the first evacuated chamber being maintained at a pressure of approximately 10⁻² to 10⁻⁴ mbar. It would have been obvious to one of ordinary skill in the art at the time the invention was made to have the first evacuated chamber be maintained at a pressure of approximately 10⁻² to 10⁻⁴ mbar, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or working ranges involves only routine skill in the art.

As per claims 3, Eiden [091] teaches all aspects of the claim except for the first evacuated chamber being maintained at a pressure of approximately 1-2 x 10⁻³ mbar. It would have been obvious to one of ordinary skill in the art at the time the invention was made to have the first evacuated chamber be maintained at a pressure of

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approximately 1-2 x 10⁻⁴ mbar, since it has been held that discovering an optimum value of a result effective variable involves only routine skill in the art.

As per claims 4, Eiden [091] teaches the ion beam, resulting from transmitting some of the ions from the ion source through a sampling aperture (20) into an evacuated expansion chamber (15) along a first axis, being transmitted into the first evacuated chamber through a second aperture, and into the second evacuated chamber (25) through a third aperture, and wherein a gap is maintained between the third aperture and an entrance aperture of the collision cell (710). See Eiden [091] figs. 1,3-4, and 7. However, it does not specifically state that the gap be at least 2 cm. It would have been obvious to one of ordinary skill in the art at the time the invention was made to have the gap be at least 2 cm, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or working ranges involves only routine skill in the art.

As per claim 5, Eiden [091] teaches a distance being maintained between the ion source and an entrance aperture of the collision cell. See Eiden [091] fig. 7 and col. 8 lines 25-67 and col. 9 lines 1-40. However, it does not specifically state that the distance maintained should be 90 to 200 mm. It would have been obvious to one of ordinary skill in the art at the time the invention was made to have a distance of 90 to 200 mm be maintained between the ion source and an entrance aperture of the collision cell, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or working ranges involves only routine skill in the art.

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As per claim 13, Eiden [091] teaches a method of operating an ICP mass spectrometer what incorporates a collision cell pressurized with a target gas, comprising the steps of; generating, from an ion source, an ion beam including analyte ions and artefact ions, mass selecting the ion beam at an analyte mass to charge ratio, transmitting the ion beam into the collision cell, and inducing collisions between the artefact ions and the target gas to the collision cell. See Eiden [091] col. 8 lines 25-67 and col. 9 lines 1-40. Although Eiden [091] does not specifically state that mass analyzing the beam at the analyte mass to charge ratio, it would have been obvious to one of ordinary skill in the art at the time the invention was made to analyze the beam at the analyte mass to charge ratio in order to see a spectrum of the ions of interest.

As per claim 14, Eiden [091] teaches the mass selecting being achieved by passing the ion beam through a first mass selective ion optical device (60,750). See Eiden [091] figs. 1,3-4, 7, col. 8 lines 25-67 and col. 9 lines 1-40.

As per claim 15, Eiden [091] teaches all aspects of the claim except for stating that the first mass selective ion optical device being located in a first evacuated chamber maintained at a high vacuum. It does however, teach the first vacuum chamber being maintained at a high vacuum. See Eiden [091] figs. 1,3-4, 7, col. 8 lines 1-40 and col. 10 lines 25-45. Therefore, it would have been obvious to a person of ordinary skill in the art at the time the invention was made to locate the first mass selective ion optical device in a first evacuated chamber in order to increase the amount of analyte ions entering the collision cell by rejecting the artefact ions in the beam.

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As per claim 16, Eiden [091] teaches the collision cell being located in a second evacuation chamber operated at lower pressure than the first evacuated chamber and the ion beam being contained in the second evacuated chamber by a second ion optical device. See Eiden [091] figs. 1,3-4, 7, col. 9 lines 1-40 and col. 10 lines 25-45.

As per claim 17, Eiden [091] teaches all aspects of the claim except for the first evacuated chamber being maintained at a pressure of approximately 10⁻² to 10⁻⁴ mbar. It would have been obvious to one of ordinary skill in the art at the time the invention was made to have the first evacuated chamber be maintained at a pressure of approximately 10⁻² to 10⁻⁴ mbar, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or working ranges involves only routine skill in the art.

As per claim 18, Eiden [091] teaches all aspects of the claim except for the first evacuated chamber being maintained at a pressure of approximately 1-2 x 10⁻³ mbar. It would have been obvious to one of ordinary skill in the art at the time the invention was made to have the first evacuated chamber be maintained at a pressure of approximately 1-2 x 10⁻⁴ mbar, since it has been held that discovering an optimum value of a result effective variable involves only routine skill in the art.

As per claim 19, Eiden [091] teaches the ion beam, resulting from transmitting some of the ions from the ion source through a sampling aperture (20) into an evacuated expansion chamber (15) along a first axis, being transmitted into the first evacuated chamber through a second aperture, and into the second evacuated chamber (25) through a third aperture, and wherein a gap is maintained between the

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third aperture and an entrance aperture of the collision cell (710). See Eiden [091] figs. 1,3-4, and 7. However, it does not specifically state that the gap be at least 2 cm. It would have been obvious to one of ordinary skill in the art at the time the invention was made to have the gap be at least 2 cm, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or working ranges involves only routine skill in the art.

As per claim 20, Eiden [091] teaches a distance being maintained between the ion source and an entrance aperture of the collision cell. See Eiden [091] fig. 7 and col. 8 lines 25-67 and col. 9 lines 1-40. However, it does not specifically state that the distance maintained should be 90 to 200 cm. It would have been obvious to one of ordinary skill in the art at the time the invention was made to have a distance of 90 to 200 cm be maintained between the ion source and an entrance aperture of the collision cell, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or working ranges involves only routine skill in the art.

Claims 6,8-11,21-24, and 26 are rejected under 35 U.S.C. 103(a) as being unpatentable over Eiden [091] in view of Tanner [638]. As per claims 6 and 21, Eiden [091] teaches a method and apparatus comprising locating a mass-to-charge ratio analyzing means (10) in a third evacuated chamber (35) and being operated at lower pressure than the second evacuated chamber (25). See Eiden [091] fig. 7, col. 9 lines 1-40 and col. 10 lines 25-40. However, Eiden [091] does not specifically state the mass-to-charge ratio analyzing means being disposed along a second axis wherein the

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mass-to-charge ratio analyzing means includes a main filter, which preferably is an RF quadrupole. Tanner [638] does teach the mass-to-charge ratio analyzing means (66) includes a main filter (64), which preferably is an RF quadrupole. See Tanner [638] abstract, fig. 1, and col. 3 lines 55-67 and col. 4 lines 1-40. Therefore, it would have been obvious to a person of ordinary skill in the art at the time the invention was made to have the mass-to-charge ration analyzing means include a main filter which preferably is an RF quadrupole in order to further filter out artefact ions coming out of the collision cell in order to obtain a better spectrum of analyte ions. In addition it would have been obvious to use an RF quadrupole to aid in the filtering since it was know in the art that RF quadrupoles are used for filtering and guiding ions. With regards to the mass-to-charge ratio analyzing means being located along a second axis, it would have been obvious to one having ordinary skill in the art at the time the invention was made to have the mass-to-charge ratio analyzing means be located along a second axis, since it has been held that rearranging parts of an invention involves only routine skill in the art.

As per claims 8 and 22, Eiden [091] teaches the first mass selective ion optical device being an RF quadrupole. See Eiden [091] col. 8 lines 55-67.

As per claims 9 and 23, Eiden [091] teaches the second ion optical device being an RF quadrupole. See Eiden [091] fig. 7 and col. 15 lines 35-40.

As per claims 10 and 24, Eiden [091] teaches the second ion optical device being mass selective. See Eiden [091] col. 17 lines 10-25.

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As per claims 11 and 26, Eiden [091] teaches all aspect of the claim except for the second axis being offset from the first axis. It would have been obvious to one having ordinary skill in the art at the time the invention was made to have the second axis being offset from the first axis, since it has been held that rearranging parts of an invention involves only routine skill in the art.

Claims 12 and 25 is rejected under 35 U.S.C. 103(a) as being unpatentable over Eiden [091] in view of Okamoto [739]. Eiden [091] teaches all aspects of the claim except for specifically stating that the first evacuated chamber is divided into a first region adjacent to the expansion chamber containing an extractor lens driven at a negative potential, and a second region adjacent to the collision cell, by a larger diameter aperture and the aperture being sealable by means of a flat plate on an O-ring seal. Okamoto [739] teaches the first evacuated chamber being divided into a first region adjacent to the expansion chamber containing an extractor lens (90) driven by a negative potential and a second region adjacent to the collision cell by a large diameter aperture and the aperture being sealable. See Okamoto [739] fig. 3 and col. 3 lines 10-30 and 45-65. Therefore, it would have been obvious to a person of ordinary skill in the art at the time the invention was made to use have the first evacuated chamber being divided into a first region adjacent to the expansion chamber containing an extractor lens (90) driven by a negative potential and a second region adjacent to the collision cell by a large diameter aperture and the aperture being sealable in order to extract ion from the ion source and keep artefacts from entering the collision cell. With regard to the applicants' claim that the aperture is sealable by means of a flat plate on an O-ring seal,

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it is well known that O-rings are used to aid in the creating air/fluid type seals. In addition, it is obvious that a flat plate placed adjacent a hole that has a circular and planar configuration would seal a hole in a vacuum chamber due to the vacuum.

Response to Arguments

Applicant's arguments with respect to claims 1-6 and 8-12 have been considered but are most in view of the new ground(s) of rejection.

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. U.S. Patent Nos. 5,818,041 to Mordehai et al, and 6,348,688, to Vestal, are considered pertinent to the applicants' disclosure. Mordehai [041] is considered pertinent because of its discussion on a mass spectrometer system and method for transporting and analyzing ions. Vestal [688] is considered pertinent because of an ion selector in communication with a collision cell, which is in communication with a mass analyzer.

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not

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mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Anthony Quash whose telephone number is (703)-308-6555. The examiner can normally be reached on M-F from 9 a.m. to 5 p.m.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John R. Lee, can be reached on (703)-308-4116. Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703)-308-0956.

A. Quash 11/4/02

/ JOHN R. LEE

SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800